

# NCV8154

## Dual 300 mA, Low I<sub>Q</sub>, Low Dropout, Dual Input Voltage Regulator

The NCV8154 is 300 mA, Dual Output Linear Voltage Regulator that offers two independent input pins and provides a very stable and accurate voltage with ultra low noise and very high Power Supply Rejection Ratio (PSRR) suitable for RF applications. The NCV8154 is suitable for powering RF blocks of automotive infotainment systems and other power sensitive device. Due to low power consumption the NCV8154 offers high efficiency and low thermal dissipation.

### Features

- Operating Input Voltage Range: 1.9 V to 5.25 V
- Two Independent Input Voltage Pins
- Two Independent Output Voltage (for detail please refer to Ordering Information)
- Low I<sub>Q</sub> of typ. 55  $\mu$ A per Channel
- High PSRR: 75 dB at 1 kHz
- Very Low Dropout: 140 mV Typical at 300 mA
- Thermal Shutdown and Current Limit Protections
- Stable with a 1  $\mu$ F Ceramic Output Capacitor
- Available in DFN10 3  $\times$  3 mm Package
- Active Output Discharge for Fast Output Turn-Off
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-free Devices

### Typical Applications

- Applications Requiring Wettable Flanks for Enhanced Visual Inspection
- Wireless LAN, Bluetooth<sup>®</sup>, ZigBee<sup>®</sup> Interfaces
- Automotive Infotainment Systems

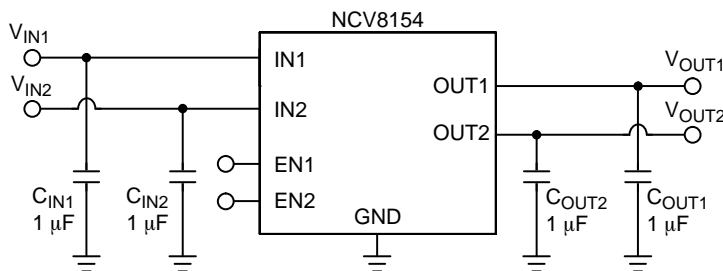


Figure 1. Typical Application Schematic



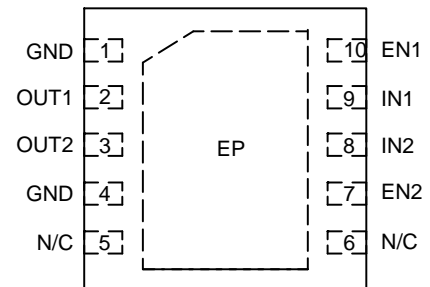
ON Semiconductor<sup>®</sup>

[www.onsemi.com](http://www.onsemi.com)



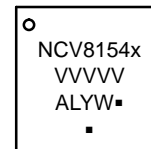
DFN10, 3x3  
CASE 485C

### PIN CONNECTIONS



DFN10  
(Top View)

### MARKING DIAGRAM



x = NCV8154N – Non wettable flank  
= NCV8154W – Wettable flank

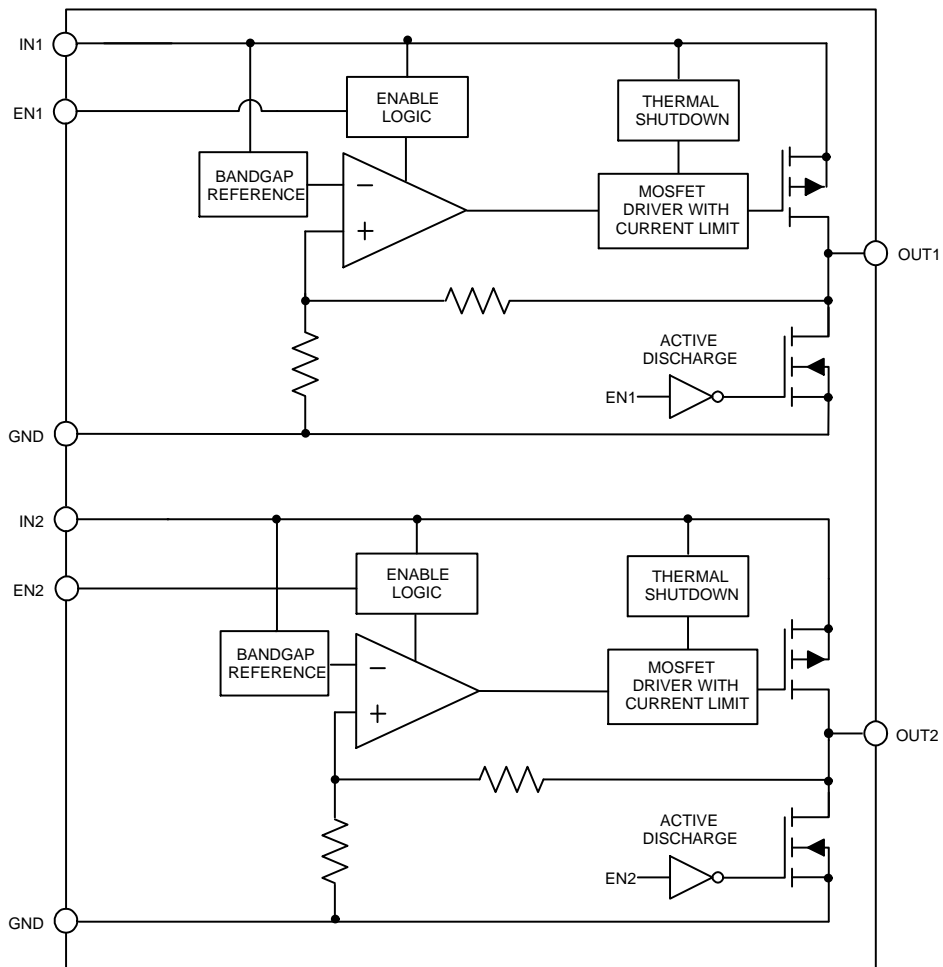
VVVVV = Voltage Option  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 15 of this data sheet.

# NCV8154



**Figure 2. Simplified Schematic Block Diagram**

**Table 1. PIN FUNCTION DESCRIPTION**

Pin No.	Pin Name	Description
1	GND	Power supply ground. Soldered to the copper plane allows for effective heat dissipation.
2	OUT1	Regulated output voltage of the first channel. A small 1 $\mu$ F ceramic capacitor is needed from this pin to ground to assure stability.
3	OUT2	Regulated output voltage of the second channel. A small 1 $\mu$ F ceramic capacitor is needed from this pin to ground to assure stability.
4	GND	Power supply ground. Soldered to the copper plane allows for effective heat dissipation.
5,6	N/C	Not connected, can be tied to ground plane to improve thermal dissipation.
7	EN2	Driving EN2 over 0.9 V turns-on OUT2. Driving EN below 0.4 V turns-off the OUT2 and activates the active discharge.
8	IN2	Inputs pin for second channel. It is recommended to connect 1 $\mu$ F ceramic capacitor close to the device pin.
9	IN1	Inputs pin for first channel. It is recommended to connect 1 $\mu$ F ceramic capacitor close to the device pin.
10	EN1	Driving EN1 over 0.9 V turns-on OUT1. Driving EN below 0.4 V turns-off the OUT1 and activates the active discharge.
-	EXP	Exposed pad must be tied to ground. Soldered to the copper plane allows for effective thermal dissipation.

# NCV8154

**Table 2. ABSOLUTE MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	$V_{IN1}, V_{IN2}$	-0.3 V to 6 V	V
Output Voltage	$V_{OUT1}, V_{OUT2}$	-0.3 V to $V_{IN} + 0.3$ V or 6 V	V
Enable Inputs	$V_{EN1}, V_{EN2}$	-0.3 V to $V_{IN} + 0.3$ V or 6 V	V
Output Short Circuit Duration	$t_{SC}$	Indefinite	s
Maximum Junction Temperature	$T_{J(MAX)}$	125	°C
Storage Temperature	$T_{STG}$	-55 to 150	°C
ESD Capability, Human Body Model (Note 2)	$ESD_{HBM}$	2,000	V
ESD Capability, Machine Model (Note 2)	$ESD_{MM}$	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
2. This device series incorporates ESD protection and is tested by the following methods:  
 ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)  
 ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)  
 Latchup Current Maximum Rating tested per JEDEC standard: JESD78.

**Table 3. THERMAL CHARACTERISTICS** (Note 3)

Rating	Symbol	Value	Unit
Thermal Characteristics, DFN10 3 × 3 mm, Thermal Resistance, Junction-to-Air	$\theta_{JA}$	109	°C/W

3. Single component mounted on 1 oz, FR4 PCB with 645 mm<sup>2</sup> Cu area.

**Table 4. ELECTRICAL CHARACTERISTICS**

( $-40^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C}$ ;  $V_{IN} = V_{OUT(NOM)} + 1\text{ V}$  or  $2.5\text{ V}$ , whichever is greater;  $V_{EN} = 0.9\text{ V}$ ,  $I_{OUT} = 1\text{ mA}$ ,  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$ . Typical values are at  $T_J = +25^{\circ}\text{C}$ . Min/Max values are specified for  $T_J = -40^{\circ}\text{C}$  and  $T_J = 125^{\circ}\text{C}$  respectively.) (Note 4)

Parameter	Test Conditions		Symbol	Min	Typ	Max	Unit
Operating Input Voltage			$V_{IN}$	1.9		5.25	V
Output Voltage Accuracy	$-40^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C}$	$V_{OUT} > 2\text{ V}$	$V_{OUT}$	-3		+3	%
		$V_{OUT} \leq 2\text{ V}$		-60		+60	mV
Line Regulation	$V_{OUT} + 0.5\text{ V} \leq V_{IN} \leq 5\text{ V}$		Reg <sub>LINE</sub>		0.02	0.2	%/V
Load Regulation	$I_{OUT} = 1\text{ mA}$ to $300\text{ mA}$		Reg <sub>LOAD</sub>		15	40	mV
Dropout Voltage (Note 5)	$I_{OUT} = 300\text{ mA}$	$V_{OUT(nom)} = 1.8\text{ V}$	$V_{DO}$		335	430	mV
		$V_{OUT(nom)} = 2.8\text{ V}$			160	290	
		$V_{OUT(nom)} = 3.3\text{ V}$			140	270	
Output Current Limit	$V_{OUT} = 90\% V_{OUT(nom)}$		$I_{CL}$		400		mA
Quiescent Current	$I_{OUT} = 0\text{ mA}$ , $EN1 = V_{IN}$ , $EN2 = 0\text{ V}$ or $EN2 = V_{IN}$ , $EN1 = 0\text{ V}$		$I_Q$		55	100	$\mu\text{A}$
	$I_{OUT1} = I_{OUT2} = 0\text{ mA}$ , $V_{EN1} = V_{EN2} = V_{IN}$		$I_Q$		110	200	
Shutdown current (Note 6)	$V_{EN} \leq 0.4\text{ V}$ , $V_{IN} = 5.25\text{ V}$		$I_{DIS}$		0.1	1	$\mu\text{A}$
EN Pin Threshold Voltage High Threshold Low Threshold	$V_{EN}$ Voltage increasing $V_{EN}$ Voltage decreasing		$V_{EN\_HI}$ $V_{EN\_LO}$	0.9		0.4	V
EN Pin Input Current	$V_{EN} = V_{IN} = 5.25\text{ V}$		$I_{EN}$		0.3	1.0	$\mu\text{A}$
Power Supply Rejection Ratio	$V_{IN} = V_{OUT} + 1\text{ V}$ for $V_{OUT} > 2\text{ V}$ , $V_{IN} = 2.5\text{ V}$ , for $V_{OUT} \leq 2\text{ V}$ , $I_{OUT} = 10\text{ mA}$	$f = 1\text{ kHz}$	PSRR		75		dB
Output Noise Voltage	$f = 10\text{ Hz}$ to $100\text{ kHz}$		$V_N$		75		$\mu\text{V}_{rms}$
Active Discharge Resistance	$V_{IN} = 4\text{ V}$ , $V_{EN} < 0.4\text{ V}$		$R_{DIS}$		50		$\Omega$
Thermal Shutdown Temperature	Temperature increasing from $T_J = +25^{\circ}\text{C}$		$T_{SD}$		160		$^{\circ}\text{C}$
Thermal Shutdown Hysteresis	Temperature falling from $T_{SD}$		$T_{SDH}$	-	20	-	$^{\circ}\text{C}$

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Performance guaranteed over the indicated operating temperature range by design and/or characterization. Production tested at  $T_J = T_A = 25^{\circ}\text{C}$ . Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
5. Characterized when  $V_{OUT}$  falls 100 mV below the regulated voltage at  $V_{IN} = V_{OUT(NOM)} + 1\text{ V}$ .
6. Shutdown Current is the current flowing into the IN pin when the device is in the disable state.

TYPICAL CHARACTERISTICS

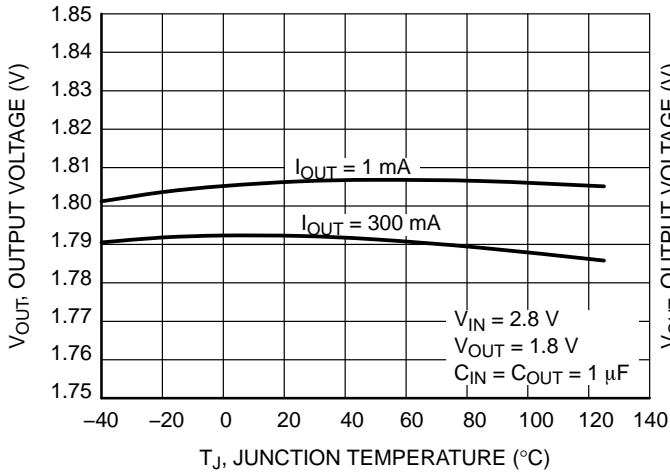


Figure 3. Output Voltage vs. Temperature  
V<sub>OUT</sub> = 1.8 V

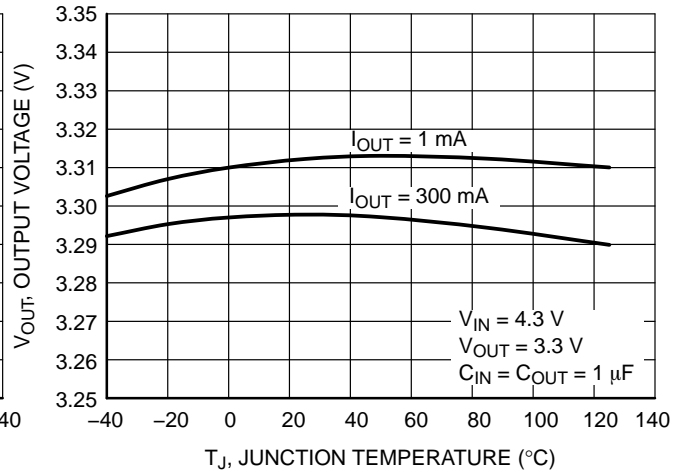


Figure 4. Output Voltage vs. Temperature  
V<sub>OUT</sub> = 3.3 V

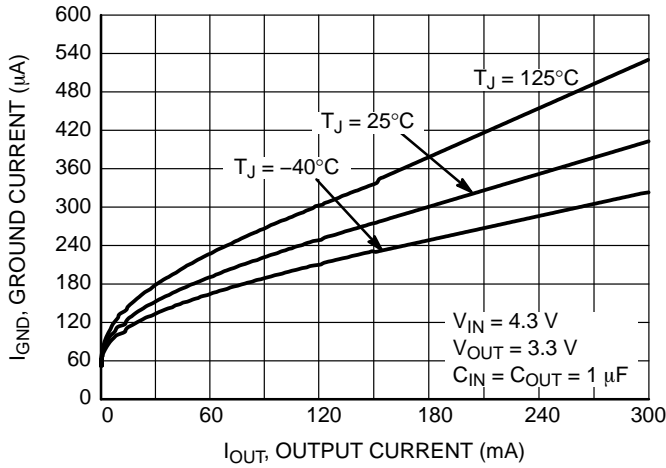


Figure 5. Ground Current vs. Output Current

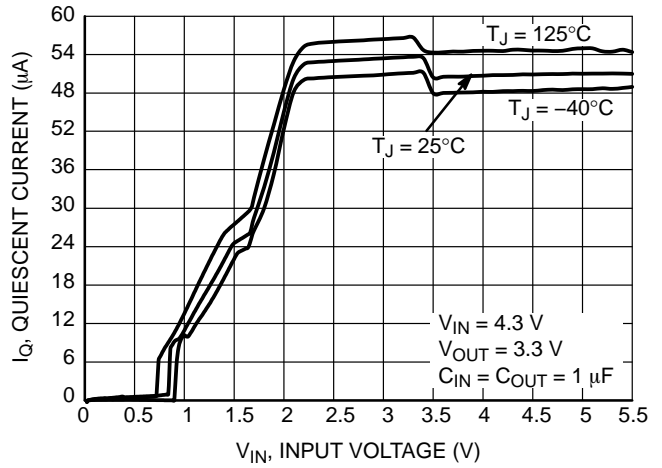


Figure 6. Quiescent Current vs. Input Voltage

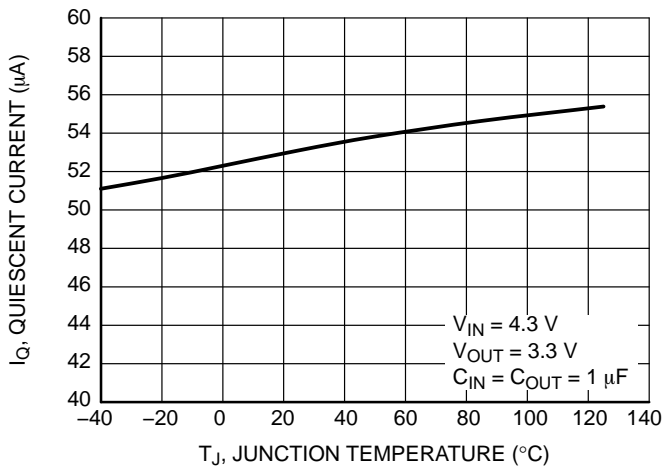


Figure 7. Quiescent Current vs. Temperature

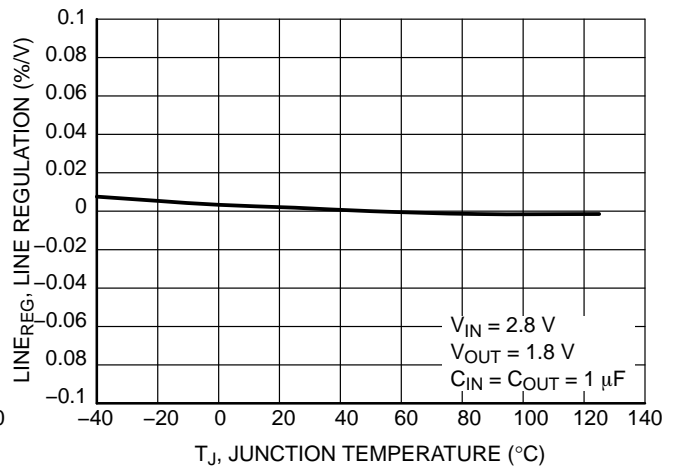


Figure 8. Line Regulation vs. Temperature  
V<sub>OUT</sub> = 1.8 V

TYPICAL CHARACTERISTICS

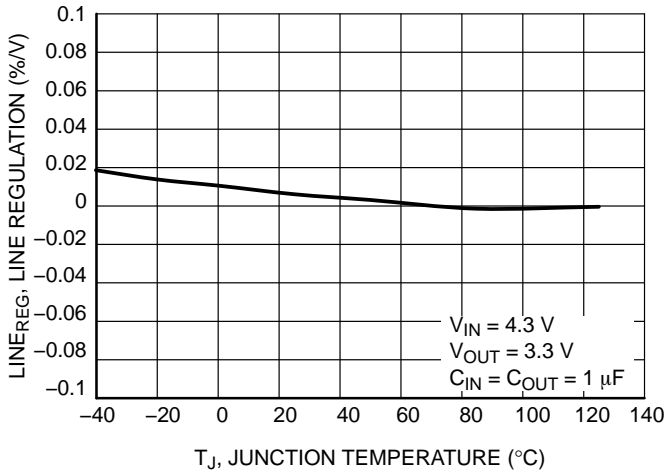


Figure 9. Line Regulation vs. Temperature  
V<sub>OUT</sub> = 3.3 V

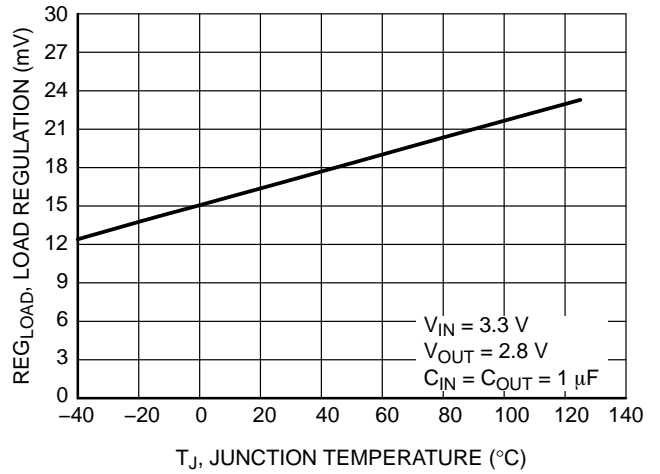


Figure 10. Load Regulation vs. Temperature  
V<sub>OUT</sub> = 2.8 V

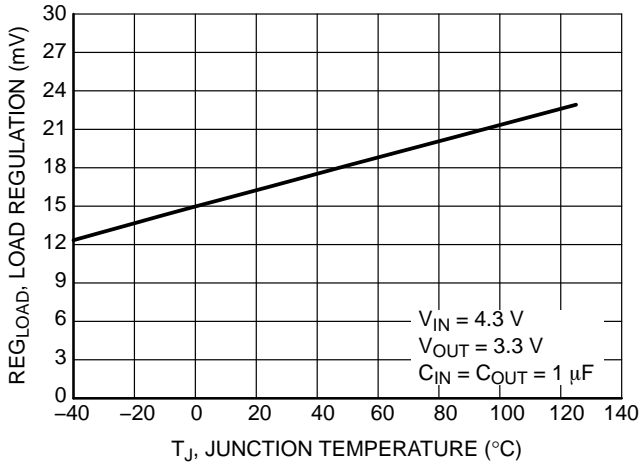


Figure 11. Load Regulation vs. Temperature  
V<sub>OUT</sub> = 3.3 V

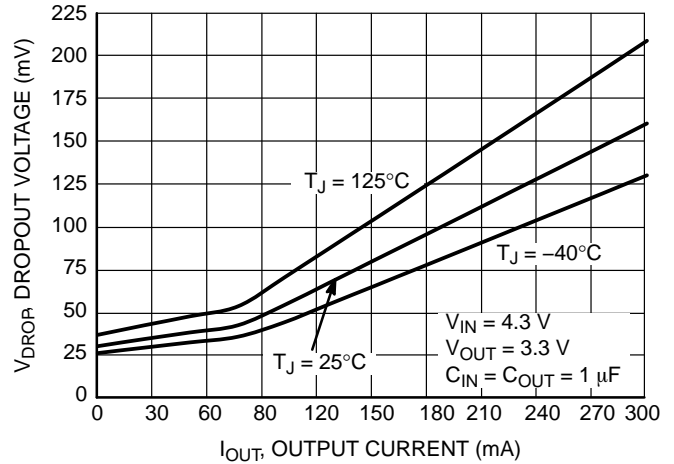


Figure 12. Dropout Voltage vs. Output Current

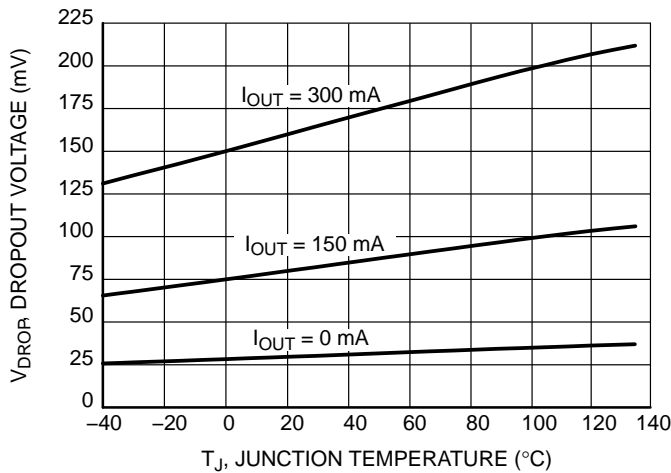


Figure 13. Dropout Voltage vs. Temperature

TYPICAL CHARACTERISTICS

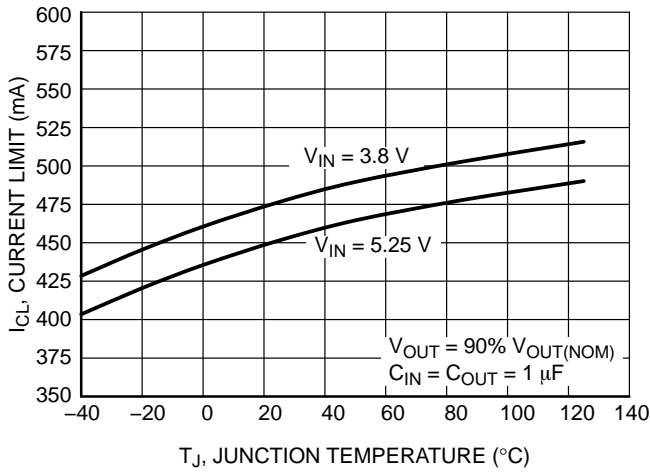


Figure 14. Current Limit vs. Temperature

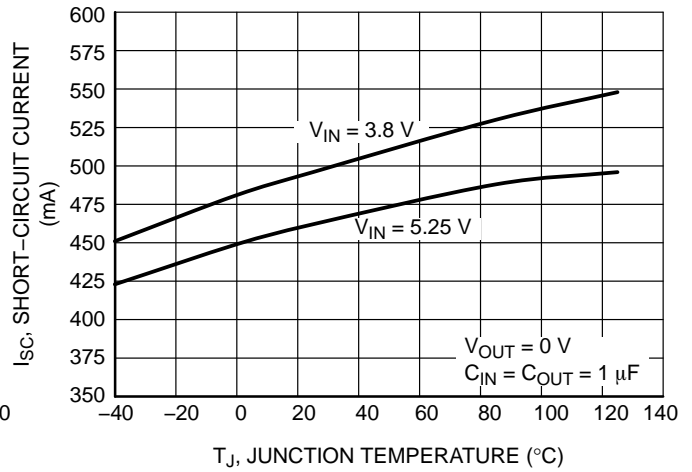


Figure 15. Short-Circuit Current vs. Temperature

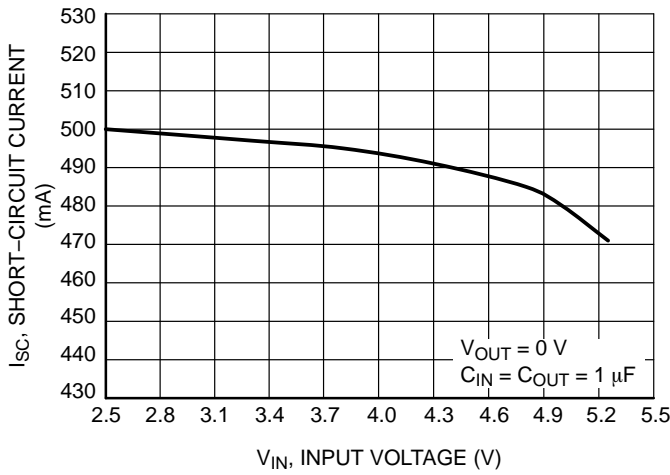


Figure 16. Short-Circuit Current vs. Input Voltage

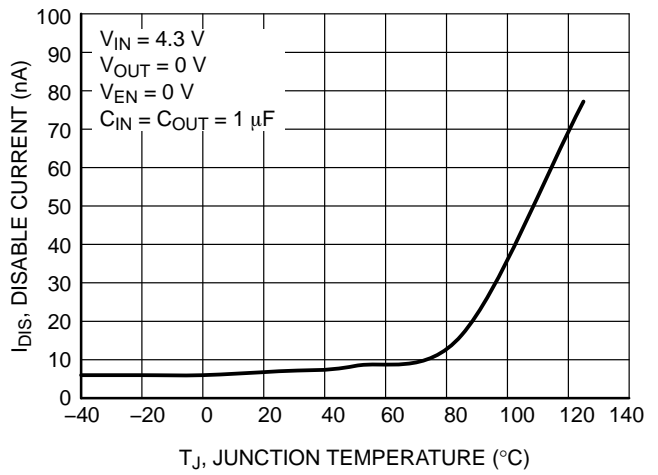


Figure 17. Disable Current vs. Temperature

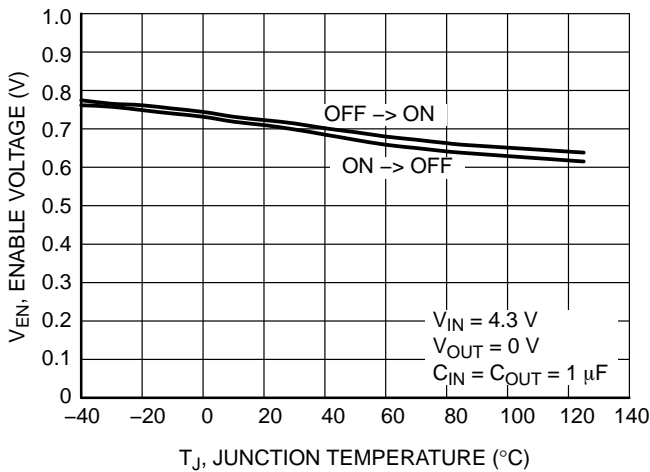


Figure 18. Enable Thresholds vs. Temperature

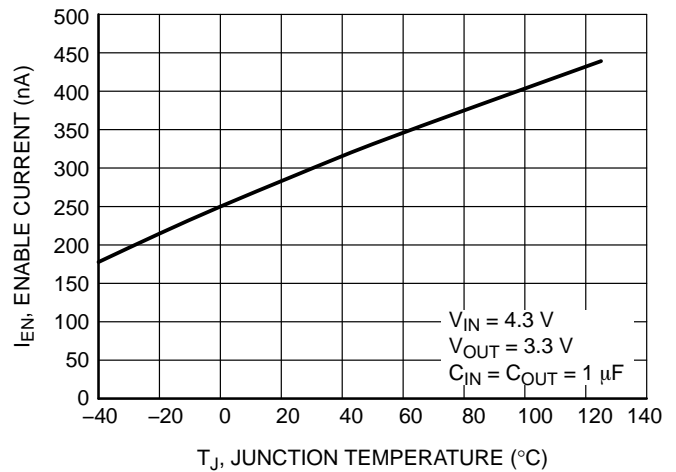


Figure 19. Current to Enable Pin vs. Temperature

TYPICAL CHARACTERISTICS

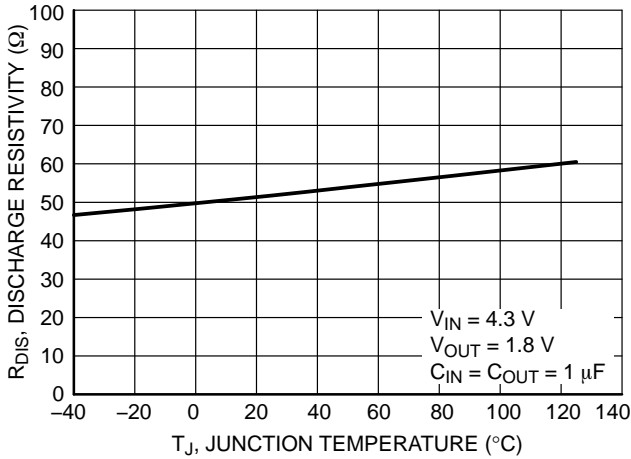


Figure 20. Discharge Resistivity vs. Temperature

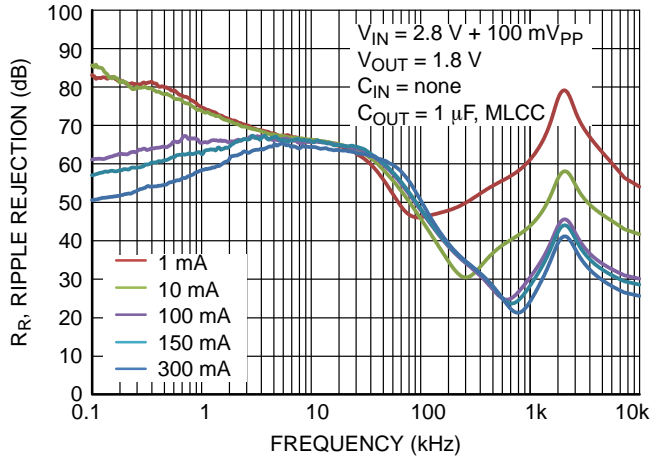


Figure 21. Power Supply Rejection Ratio,  $V_{OUT} = 1.8 V$

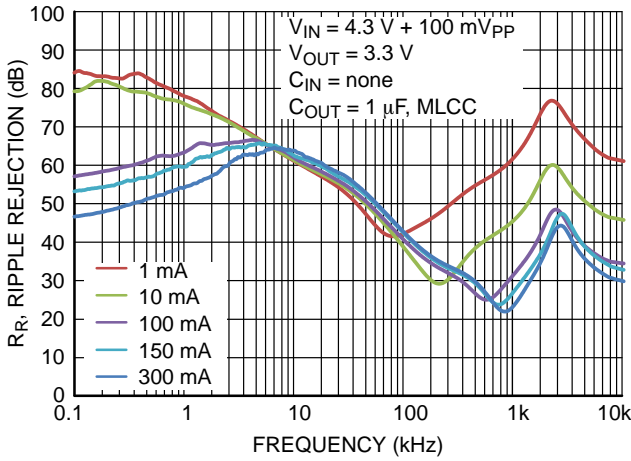


Figure 22. Power Supply Rejection Ratio,  $V_{OUT} = 3.3 V$

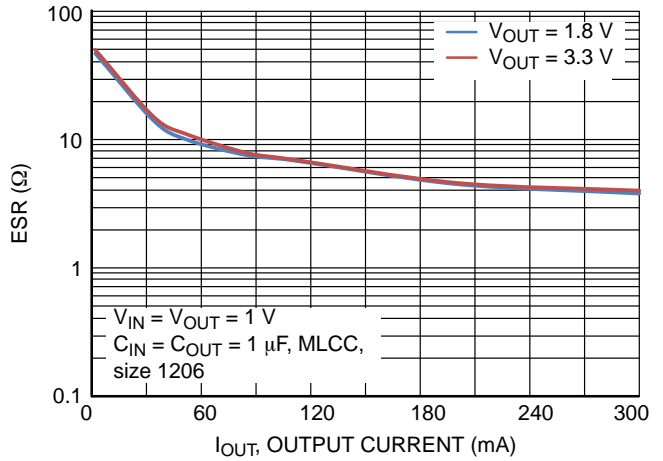


Figure 23. Output Capacitor ESR vs. Output Current

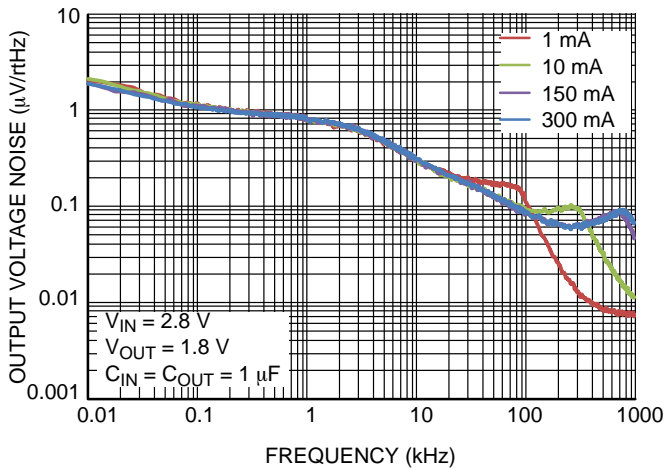
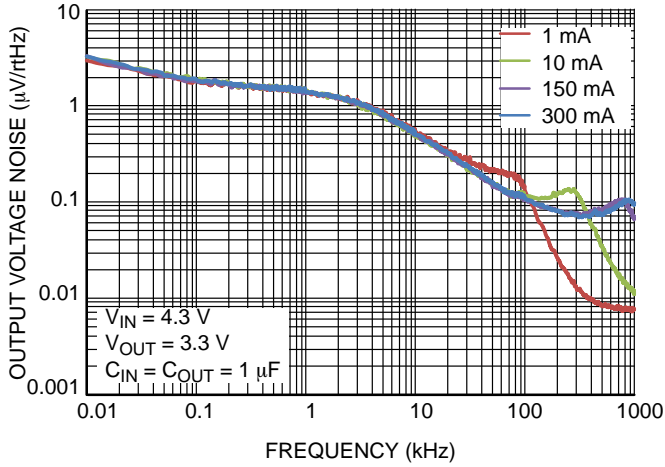


Figure 24. Output Voltage Noise Spectral Density for  $V_{OUT} = 2.8 V$ ,  $C_{OUT} = 1 \mu F$

$I_{OUT}$	RMS Output Noise ( $\mu V$ )	
	10 Hz – 100 kHz	100 Hz – 100 kHz
1 mA	77.84	77.28
10 mA	71.71	70.48
150 mA	71.95	70.88
300 mA	72.71	71.67



TYPICAL CHARACTERISTICS



I <sub>OUT</sub>	RMS Output Noise (µV)	
	10 Hz – 100 kHz	100 Hz – 100 kHz
1 mA	119.7	117.87
10 mA	113.47	111.47
150 mA	113.84	112.05
300 mA	115.95	114.03

Figure 25. Output Voltage Noise Spectral Density for V<sub>OUT</sub> = 3.3 V, C<sub>OUT</sub> = 1 µF

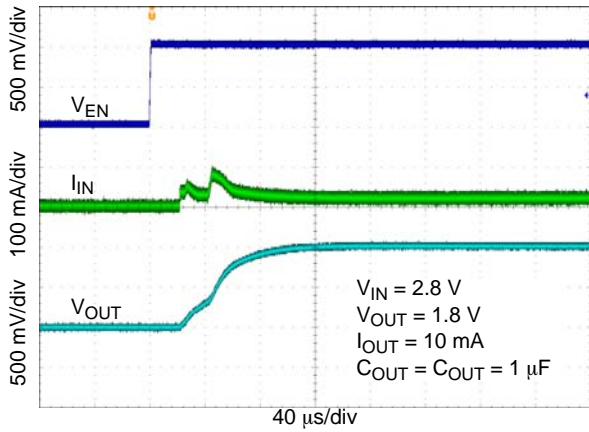


Figure 26. Enable Turn-on Response – V<sub>OUT</sub> = 1.8 V, C<sub>OUT</sub> = 1 µF

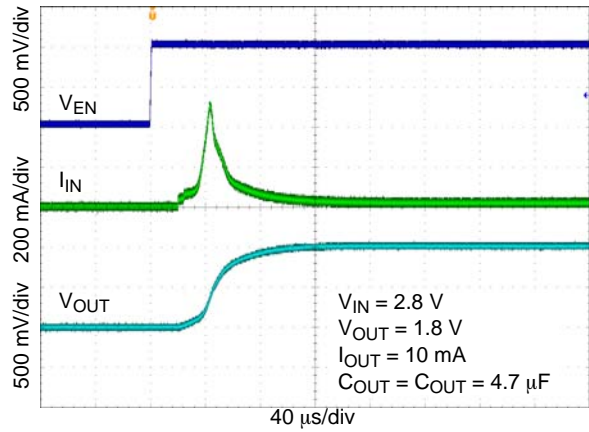


Figure 27. Enable Turn-on Response – V<sub>OUT</sub> = 1.8 V, C<sub>OUT</sub> = 4.7 µF

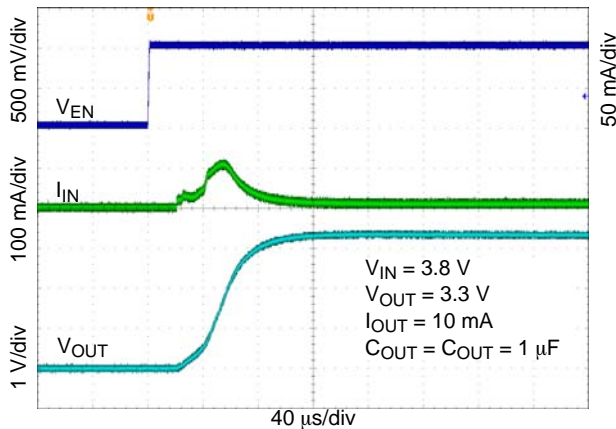


Figure 28. Enable Turn-on Response – V<sub>OUT</sub> = 3.3 V, C<sub>OUT</sub> = 1 µF

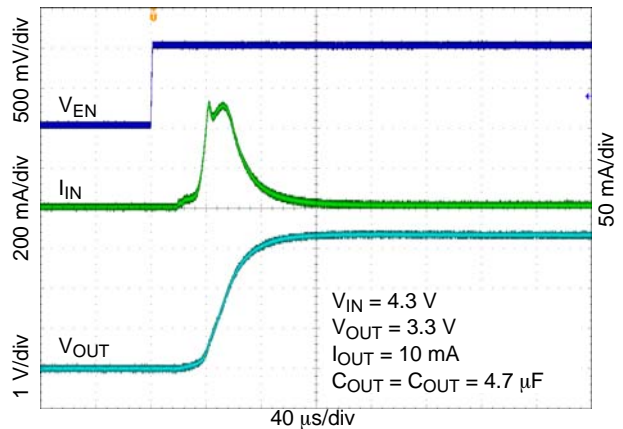


Figure 29. Enable Turn-on Response – V<sub>OUT</sub> = 3.3 V, C<sub>OUT</sub> = 4.7 µF

TYPICAL CHARACTERISTICS

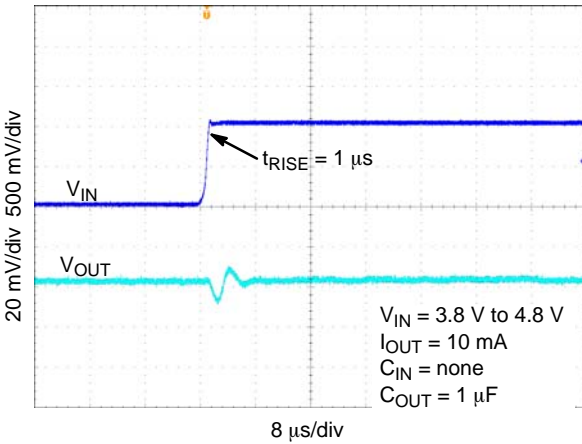


Figure 30. Line Transient Response – Rising Edge,  $V_{OUT} = 3.3\text{ V}$ ,  $I_{OUT} = 10\text{ mA}$

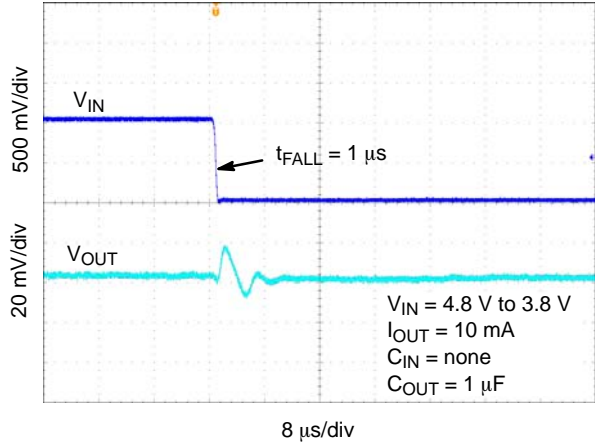


Figure 31. Line Transient Response – Falling Edge,  $V_{OUT} = 3.3\text{ V}$ ,  $I_{OUT} = 10\text{ mA}$

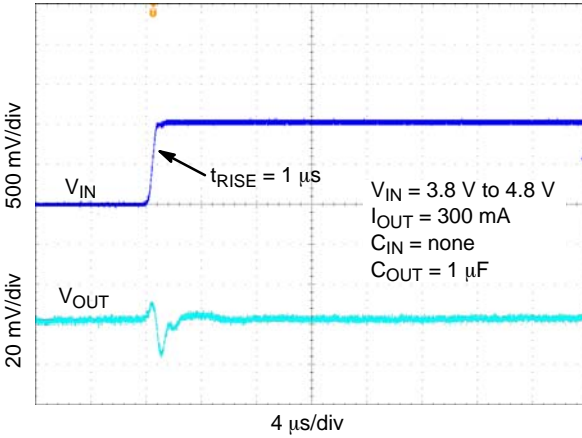


Figure 32. Line Transient Response – Rising Edge,  $V_{OUT} = 3.3\text{ V}$ ,  $I_{OUT} = 300\text{ mA}$

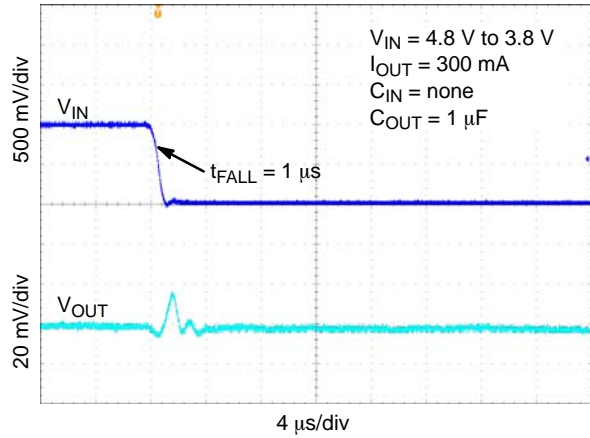


Figure 33. Line Transient Response – Falling Edge,  $V_{OUT} = 3.3\text{ V}$ ,  $I_{OUT} = 300\text{ mA}$

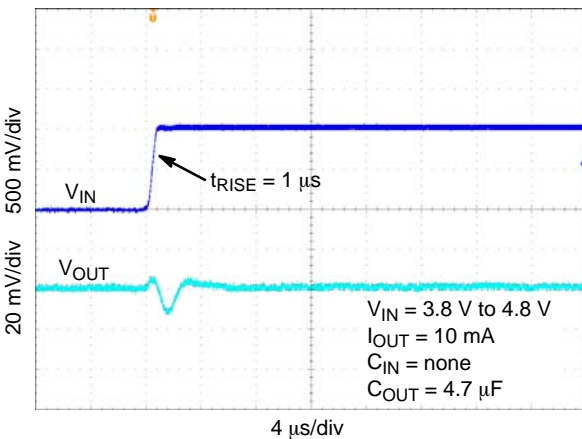


Figure 34. Line Transient Response – Rising Edge,  $V_{OUT} = 3.3\text{ V}$ ,  $I_{OUT} = 10\text{ mA}$ ,  $C_{OUT} = 4.7\text{ μF}$

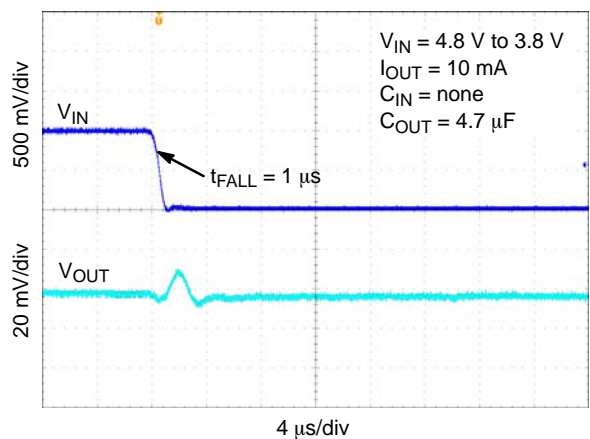


Figure 35. Line Transient Response – Falling Edge,  $V_{OUT} = 3.3\text{ V}$ ,  $I_{OUT} = 10\text{ mA}$ ,  $C_{OUT} = 4.7\text{ μF}$

TYPICAL CHARACTERISTICS

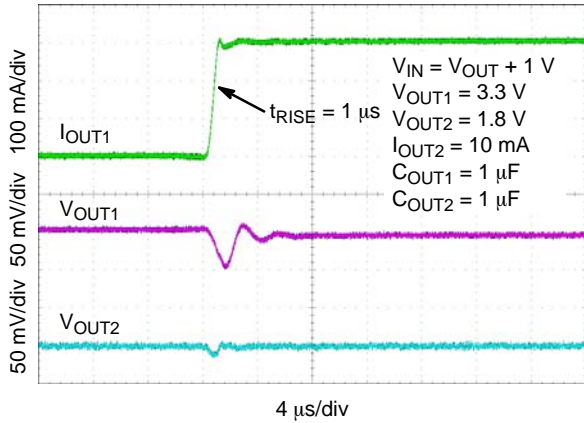


Figure 36. Load Transient Response – 1.8 V – Rising Edge,  $I_{OUT1} = 100 \mu\text{A}$  to 300 mA

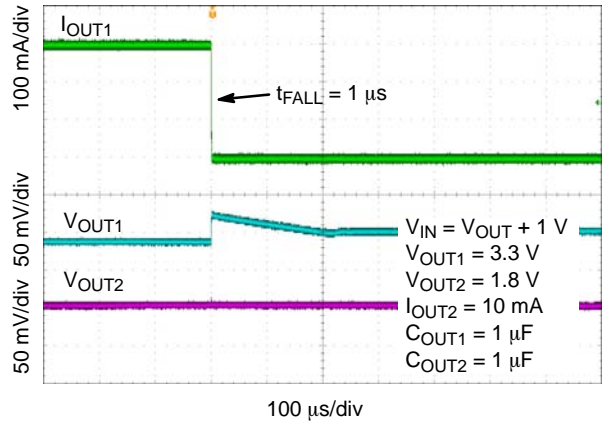


Figure 37. Load Transient Response – 1.8 V – Falling Edge,  $I_{OUT1} = 300 \text{ mA}$  to 100  $\mu\text{A}$

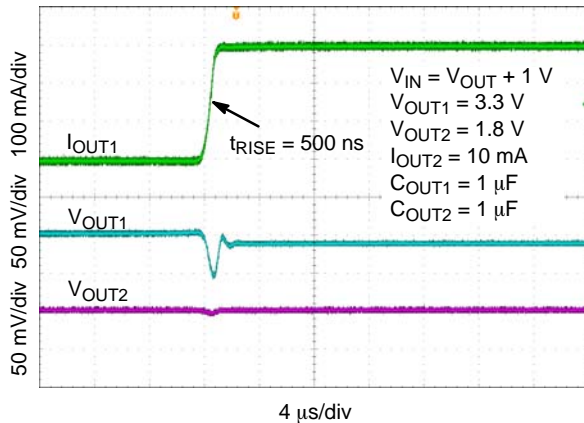


Figure 38. Load Transient Response – 1.8 V – Rising Edge,  $I_{OUT1} = 1 \text{ mA}$  to 300 mA

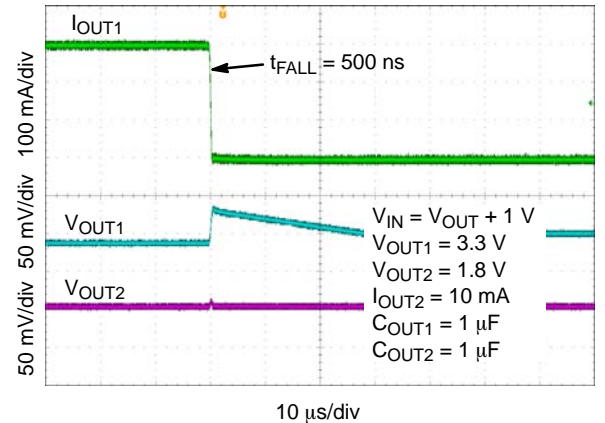


Figure 39. Load Transient Response – 1.8 V – Falling Edge,  $I_{OUT1} = 300 \text{ mA}$  to 1 mA

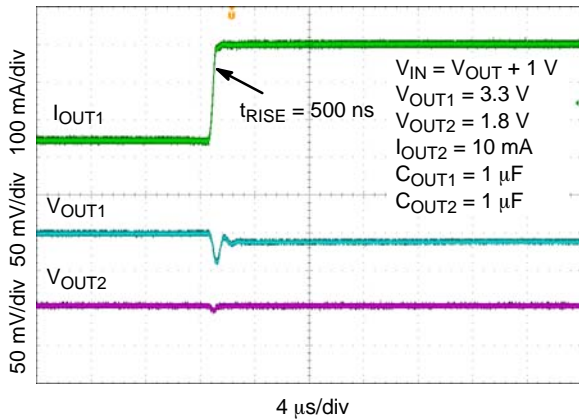


Figure 40. Load Transient Response – 1.8 V – Rising Edge,  $I_{OUT} = 50 \text{ mA}$  to 300 mA

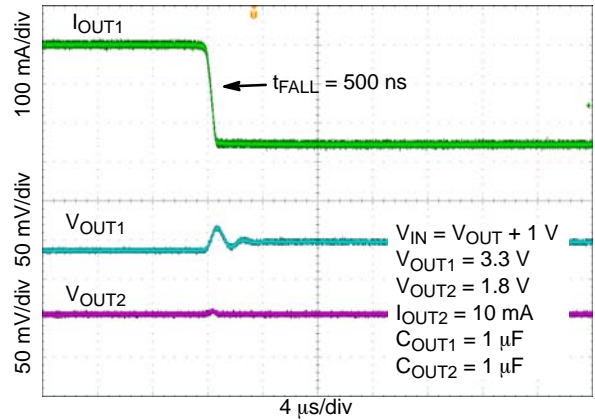


Figure 41. Load Transient Response – Falling Edge,  $I_{OUT} = 300 \text{ mA}$  to 50 mA

TYPICAL CHARACTERISTICS

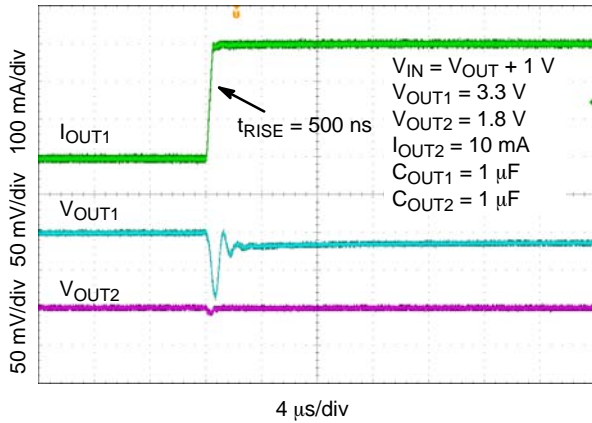


Figure 42. Load Transient Response – 3.3 V – Rising Edge,  $I_{OUT1}$  = 100  $\mu$ A to 300 mA

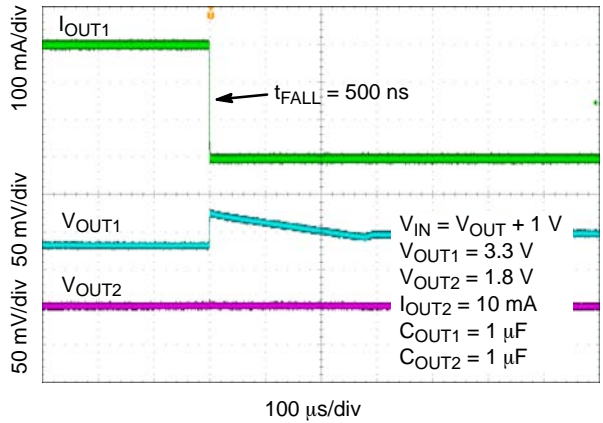


Figure 43. Load Transient Response – 3.3 V – Falling Edge,  $I_{OUT1}$  = 300 mA to 100  $\mu$ A

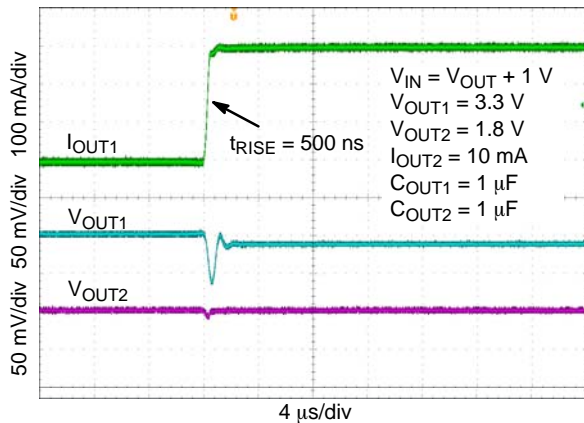


Figure 44. Load Transient Response – 3.3 V – Rising Edge,  $I_{OUT1}$  = 1 mA to 300 mA

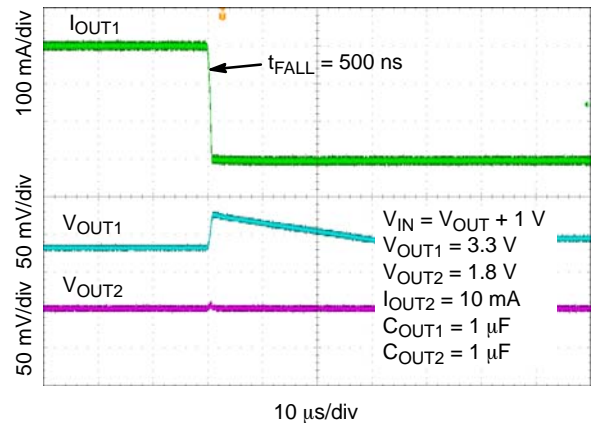


Figure 45. Load Transient Response – 3.3 V – Falling Edge,  $I_{OUT1}$  = 300 mA to 1 mA

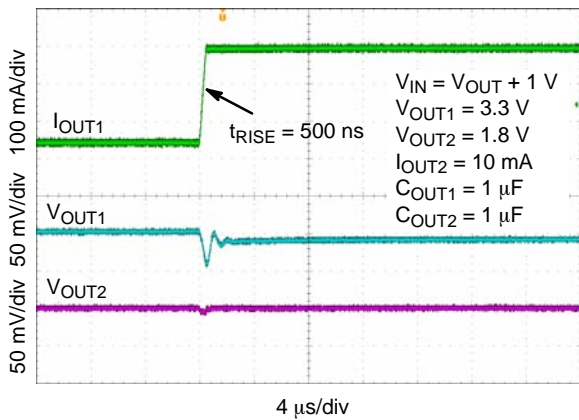


Figure 46. Load Transient Response – 3.3 V – Rising Edge,  $I_{OUT}$  = 50 mA to 300 mA

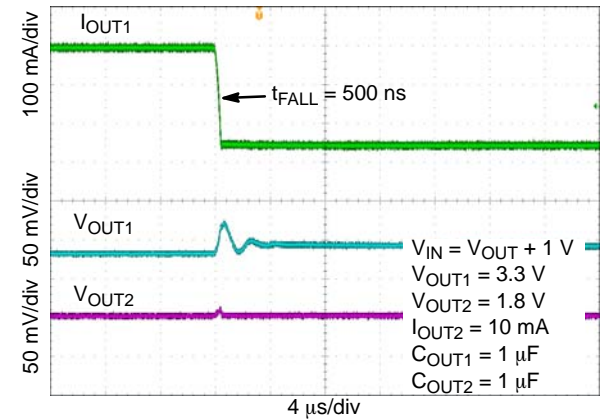
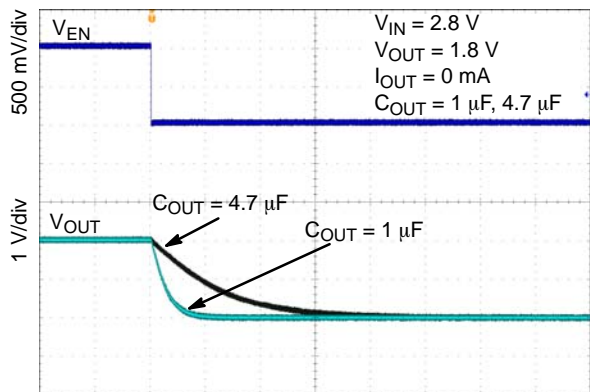


Figure 47. Load Transient Response – Falling Edge,  $I_{OUT}$  = 300 mA to 50 mA

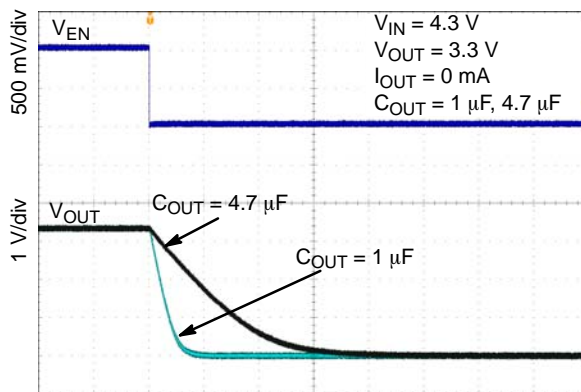


TYPICAL CHARACTERISTICS



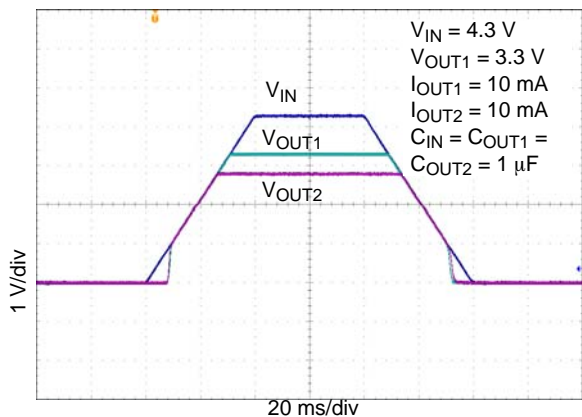
200  $\mu\text{s}/\text{div}$

Figure 48. Enable Turn-off,  $V_{OUT} = 1.8 \text{ V}$



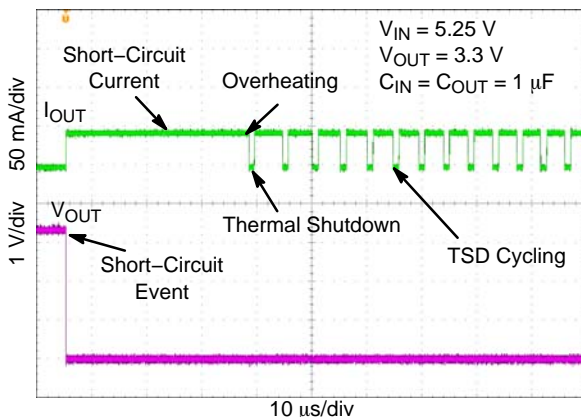
200  $\mu\text{s}/\text{div}$

Figure 49. Enable Turn-off,  $V_{OUT} = 3.3 \text{ V}$



20  $\text{ms}/\text{div}$

Figure 50. Turn-on/off – Slow Rising  $V_{IN}$



10  $\mu\text{s}/\text{div}$

Figure 51. Short-Circuit and Thermal Shutdown

## General

The NCV8154 is a dual output high performance 300 mA Low Dropout Linear Regulator. This device delivers very high PSRR (75 dB at 1 kHz) and excellent dynamic performance as load/line transients. In connection with low quiescent current this device is very suitable for various battery powered applications such as tablets, cellular phones, wireless and many others. Each output is fully protected in case of output overload, output short circuit condition and overheating, assuring a very robust design. The NCV8154 device is housed in DFN10 3 x3 mm package which is useful for space constrained application.

## Input Capacitor Selection (C<sub>IN</sub>)

It is recommended to connect at least a 1 μF Ceramic X5R or X7R capacitor as close as possible to the IN pin of the device. This capacitor will provide a low impedance path for unwanted AC signals or noise modulated onto constant input voltage. There is no requirement for the min. or max. ESR of the input capacitor but it is recommended to use ceramic capacitors for their low ESR and ESL. A good input capacitor will limit the influence of input trace inductance and source resistance during sudden load current changes. Larger input capacitor may be necessary if fast and large load transients are encountered in the application.

## Output Decoupling (C<sub>OUT</sub>)

The NCV8154 requires an output capacitor for each output connected as close as possible to the output pin of the regulator. The recommended capacitor value is 1 μF and X7R or X5R dielectric due to its low capacitance variations over the specified temperature range. The NCV8154 is designed to remain stable with minimum effective capacitance of 0.33 μF to account for changes with temperature, DC bias and package size. Especially for small package size capacitors such as 0201 the effective capacitance drops rapidly with the applied DC bias.

There is no requirement for the minimum value of Equivalent Series Resistance (ESR) for the C<sub>OUT</sub> but the maximum value of ESR should be less than 3 Ω. Larger output capacitors and lower ESR could improve the load transient response or high frequency PSRR. It is not recommended to use tantalum capacitors on the output due to their large ESR. The equivalent series resistance of tantalum capacitors is also strongly dependent on the temperature, increasing at low temperature.

## Enable Operation

The NCV8154 uses the dedicated EN pin for each output channel. This feature allows driving outputs separately.

If the EN pin voltage is <0.4 V the device is guaranteed to be disabled. The pass transistor is turned-off so that there is virtually no current flow between the IN and OUT. The active discharge transistor is active so that the output voltage V<sub>OUT</sub> is pulled to GND through a 50 Ω resistor. In the disable state the device consumes as low as typ. 10 nA from the V<sub>IN</sub>.

If the EN pin voltage >0.9 V the device is guaranteed to be enabled. The NCV8154 regulates the output voltage and the active discharge transistor is turned-off.

The both EN pin has internal pull-down current source with typ. value of 300 nA which assures that the device is turned-off when the EN pin is not connected. In the case where the EN function isn't required the EN should be tied directly to IN.

## Output Current Limit

Output Current is internally limited within the IC to a typical 400 mA. The NCV8154 will source this amount of current measured with a voltage drops on the 90% of the nominal V<sub>OUT</sub>. If the Output Voltage is directly shorted to ground (V<sub>OUT</sub> = 0 V), the short circuit protection will limit the output current to 520 mA (typ). The current limit and short circuit protection will work properly over whole temperature range and also input voltage range. There is no limitation for the short circuit duration. This protection works separately for each channel. Short circuit on the one channel do not influence second channel which will work according to specification.

## Thermal Shutdown

When the die temperature exceeds the Thermal Shutdown threshold (T<sub>SD</sub> – 160°C typical), Thermal Shutdown event is detected and the affected channel is turn-off. Second channel still working. The channel which is overheated will remain in this state until the die temperature decreases below the Thermal Shutdown Reset threshold (T<sub>SDU</sub> – 140°C typical). Once the device temperature falls below the 140°C the appropriate channel is enabled again. The thermal shutdown feature provides the protection from a catastrophic device failure due to accidental overheating. This protection is not intended to be used as a substitute for proper heat sinking. The long duration of the short circuit condition to some output channel could cause turn-off other output when heat sinking is not enough and temperature of the other output reach T<sub>SD</sub> temperature.

## Power Dissipation

As power dissipated in the NCV8154 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part.

The maximum power dissipation the NCV8154 can handle is given by:

$$P_{D(MAX)} = \frac{[T_{J(MAX)} - T_A]}{\theta_{JA}} \quad (\text{eq. 1})$$

The power dissipated by the NCV8154 for given application conditions can be calculated from the following equations:

$$P_D \approx (V_{IN1} \cdot I_{GND1}) + (V_{IN2} \cdot I_{GND2}) + I_{OUT1}(V_{IN1} - V_{OUT1}) + I_{OUT2}(V_{IN2} - V_{OUT2}) \quad (\text{eq. 2})$$

## NCV8154

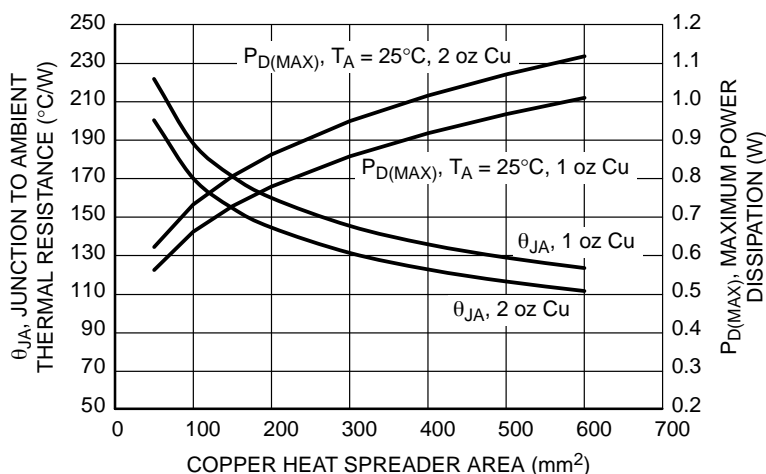


Figure 52.  $\theta_{JA}$  vs. Copper Area

### Reverse Current

The PMOS pass transistor has an inherent body diode which will be forward biased in the case that  $V_{OUT} > V_{IN}$ . Due to this fact in cases, where the extended reverse current condition can be anticipated the device may require additional external protection.

### Power Supply Rejection Ratio

The NCV8154 features very good Power Supply Rejection ratio. If desired the PSRR at higher frequencies in the range 100 kHz – 10 MHz can be tuned by the selection of  $C_{OUT}$  capacitor and proper PCB layout.

### Turn-On Time

The turn-on time is defined as the time period from EN assertion to the point in which  $V_{OUT}$  will reach 98% of its nominal value. This time is dependent on various application conditions such as  $V_{OUT(NOM)}$ ,  $C_{OUT}$ ,  $T_A$ .

### PCB Layout Recommendations

To obtain good transient performance and good regulation characteristics place input and output capacitors close to the device pins and make the PCB traces wide. In order to minimize the solution size, use 0402 capacitors. Larger copper area connected to the pins will also improve the device thermal resistance. The actual power dissipation can be calculated from the equation above (Equation 2). Expose pad should be tied the shortest path to the GND pin.

Table 5. ORDERING INFORMATION

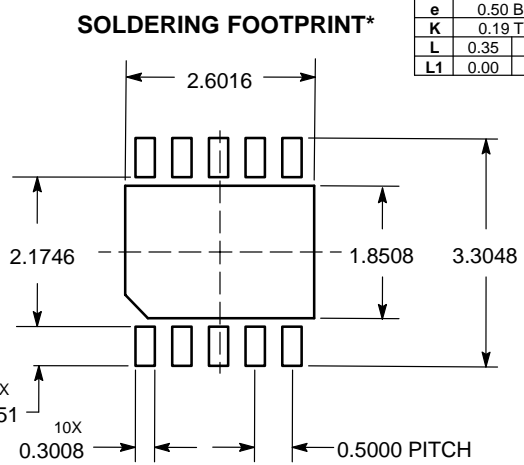
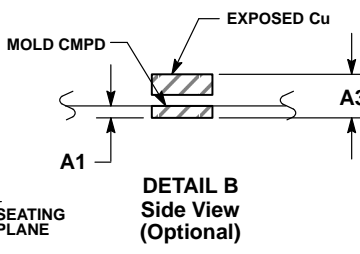
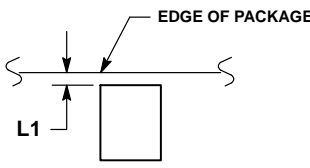
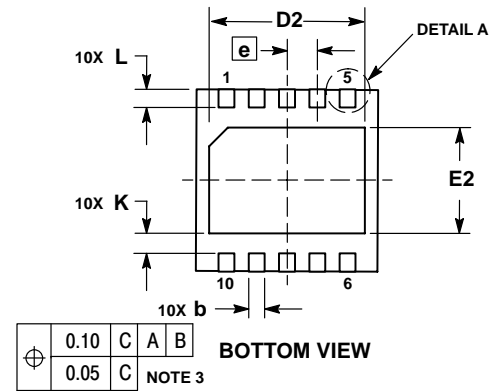
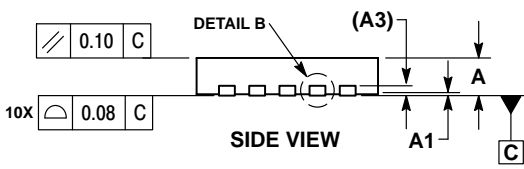
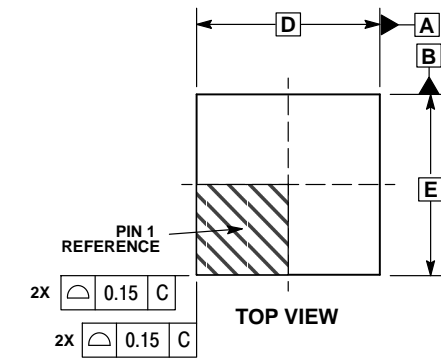
Device	Voltage Option (OUT1/OUT2)	Marking	Features	Package	Shipping <sup>†</sup>
NCV8154MW180280TBG	1.8 V / 2.8 V	8154W 1828	Wettable Flank	DFN10 (Pb-Free)	3000 / Tape & Reel
NCV8154MN300300TBG	3.0 V / 3.0 V	8154N 3030	Non-wettable Flank		
NCV8154MW300300TBG		8154W 3030	Wettable Flank		
NCV8154MN330180TBG	3.3 V / 1.8 V	8154N 3318	Non-wettable Flank		
NCV8154MW330180TBG		8154W 3318	Wettable Flank		
NCV8154MW330280TBG	3.3 V / 2.8 V	8154W 3328			
NCV8154MW330330TBG	3.3 V / 3.3 V	8154W 3333			

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NCV8154

## PACKAGE DIMENSIONS

DFN10 3x3, 0.5P  
CASE 485C  
ISSUE C



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
  4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
  5. TERMINAL b MAY HAVE MOLD COMPOUND MATERIAL ALONG SIDE EDGE. MOLD FLASHING MAY NOT EXCEED 30 MICRONS ONTO BOTTOM SURFACE OF TERMINAL b.
  6. DETAILS A AND B SHOW OPTIONAL VIEWS FOR END OF TERMINAL LEAD AT EDGE OF PACKAGE.
  7. FOR DEVICE OPN CONTAINING W OPTION, DETAIL B ALTERNATE CONSTRUCTION IS NOT APPLICABLE.

MILLIMETERS		
DIM	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.20	REF
b	0.18	0.30
D	3.00	BSC
D2	2.40	2.60
E	3.00	BSC
E2	1.70	1.90
e	0.50	BSC
K	0.19	TYP
L	0.35	0.45
L1	0.00	0.03

DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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